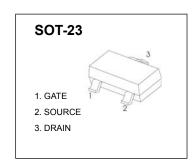


JIANGSU CHANGJIANG ELECTRONICS TECHNOLOGY CO., LTD

SOT-23 Plastic-Encapsulate MOSFETS

CJ2310 N-Channel MOSFET

| V _{(BR)DSS} | R _{DS(on)} MAX | I _D |
|----------------------|-------------------------|----------------|
| 60∨ | 105mΩ@10V | |
| | 125mΩ@4.5V | 3A |



DESCRIPTION

The CJ2310 uses advanced trench technology to provide excellent $R_{\text{DS(ON)}}$, low gate charge and operation with gate voltage as low as 2.5V. This device is suitable for use as a battery protection or in other switching application.

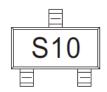
FEATURE

- High power and current handing capability
- Lead free product is acquired
- Surface mount package

APPLICATION

- Battery Switch
- DC/DC Converter

MARKING



Equivalent Circuit



Maximum ratings ($T_a=25^{\circ}C$ unless otherwise noted)

| Parameter | Symbol | Value | Unit |
|--|------------------|----------|------|
| Drain-Source Voltage | V _{DS} | 60 | V |
| Gate-Source Voltage | V_{GS} | ±20 | V |
| Continuous Drain Current | I _D | 3 | Α |
| Pulsed Drain Current (note 1) | I _{DM} | 10 | Α |
| Power Dissipation | P _D | 0.35 | W |
| Thermal Resistance from Junction to Ambient (note 2) | $R_{\theta JA}$ | 357 | °C/W |
| Junction Temperature | TJ | 150 | ℃ |
| Storage Temperature | T _{STG} | -55~+150 | ℃ |

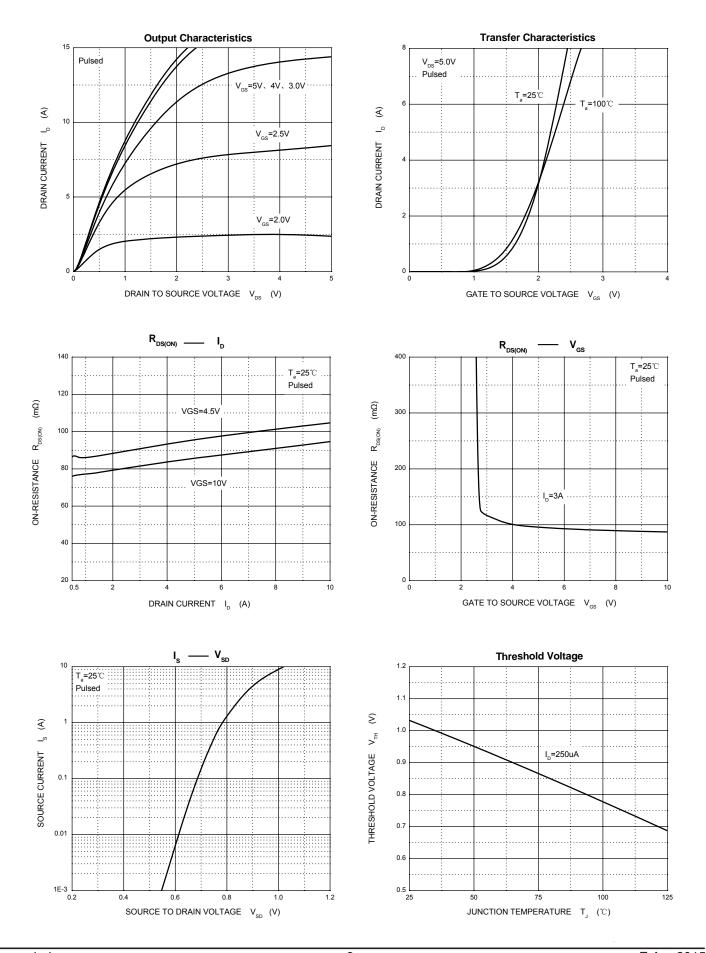
MOSFET ELECTRICAL CHARACTERISTICS

T_a =25 $^{\circ}$ C unless otherwise specified

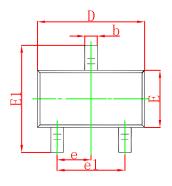
| Parameter | Symbol | Test Condition | Min | Тур | Max | Unit |
|-------------------------------------|---------------------|---|-----|------|------|------|
| STATIC CHARACTERISTICS | | | | | | |
| Drain-source breakdown voltage | V (BR)DSS | V _{GS} = 0V, I _D =250μA | 60 | | | V |
| Zero gate voltage drain current | IDSS | V _{DS} =60V,V _{GS} = 0V | | | 1 | μΑ |
| Gate-body leakage current | Igss | V _{GS} =±20V, V _{DS} = 0V | | | ±100 | nA |
| Gate threshold voltage (note 3) | V _{GS(th)} | V _{DS} =V _{GS} , I _D =250μA | 0.5 | | 2 | V |
| Drain source on registance (note 2) | Prov.) | V _{GS} =10V, I _D =3A | | | 105 | mΩ |
| Drain-source on-resistance (note 3) | RDS(on) | V _{DS} =V _{GS} , I _D =250μA 0.5 | 125 | mΩ | | |
| Forward tranconductance (note 3) | g FS | V _{DS} =15V, I _D =2A | 1.4 | | | S |
| Diode forward voltage (note 3) | V _{SD} | I _S =3A, V _{GS} = 0V | | | 1.2 | V |
| DYNAMIC CHARACTERISTICS (no | te 4) | | | | | |
| Input Capacitance | C _{iss} | | | 247 | | pF |
| Output Capacitance | C _{oss} | V _{DS} =30V,V _{GS} =0V,f =1MHz | | 34 | | pF |
| Reverse Transfer Capacitance | C _{rss} | | | 19.5 | | pF |
| SWITCHING CHARACTERISTICS (I | note 4) | | | | | |
| Turn-on delay time | td(on) | | | 6 | | ns |
| Turn-on rise time | tr | V_{GS} =10V, V_{DD} =30V, | | 15 | | ns |
| Turn-off delay time | td(off) | $I_D=1.5A,R_{GEN}=1\Omega$ | | 15 | | ns |
| Turn-off fall time | t f | | | 10 | | ns |
| Total Gate Charge | Qg | | | 6 | | nC |
| Gate-Source Charge | Q_{gs} | V _{DS} =30V,V _{GS} =4.5V,I _D =3A | | 1 | | nC |
| Gate-Drain Charge | Q_{gd} |] | | 1.3 | | nC |

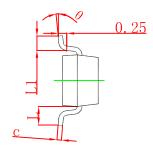
Notes:

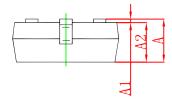
- 1. Repetitive rating: Pulse width limited by junction temperature.
- 2. Surface mounted on FR4 board , t≤10s.
- 3. Pulse Test : Pulse Width≤300µs, Duty Cycle≤0.5%.
- 4. Guaranteed by design, not subject to producting.



SOT-23 Package Outline Dimensions

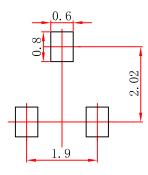






| Cumbal | Dimensions | In Millimeters | Dimensions In Inches | | |
|--------|------------|-----------------|----------------------|-------|--|
| Symbol | Min | Max | Min | Max | |
| Α | 0.900 | 1.150 | 0.035 | 0.045 | |
| A1 | 0.000 | 0.100 | 0.000 | 0.004 | |
| A2 | 0.900 | 1.050 | 0.035 | 0.041 | |
| b | 0.300 | 0.500 | 0.012 | 0.020 | |
| С | 0.080 | 0.150 | 0.003 | 0.006 | |
| D | 2.800 | 3.000 | 0.110 | 0.118 | |
| E | 1.200 | 1.400 | 0.047 | 0.055 | |
| E1 | 2.250 | 2.550 | 0.089 | 0.100 | |
| е | 0.950 |) TYP 0.037 TYP | | 7 TYP | |
| e1 | 1.800 | 2.000 | 0.071 | 0.079 | |
| L | 0.550 | REF | 0.022 | REF | |
| L1 | 0.300 | 0.500 | 0.012 | 0.020 | |
| θ | 0° | 8° | 0° | 8° | |

SOT-23 Suggested Pad Layout



Note:

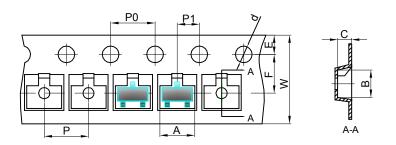
- 1. Controlling dimension: in millimeters.
- 2.General tolerance:±0.05mm.
- 3. The pad layout is for reference purposes only.

NOTICE

JCET reserve the right to make modifications,enhancements, improvements, corrections or other changes without further notice to any product herein.JCET does not assume any liability arising out of the application or use of any product described herein.

SOT-23 Tape and reel

SOT-23 Embossed Carrier Tape

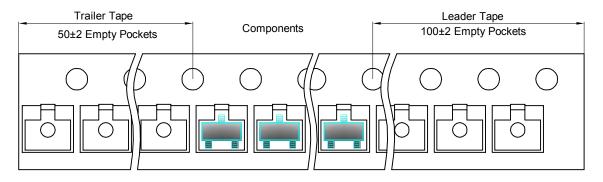


Packaging Description:

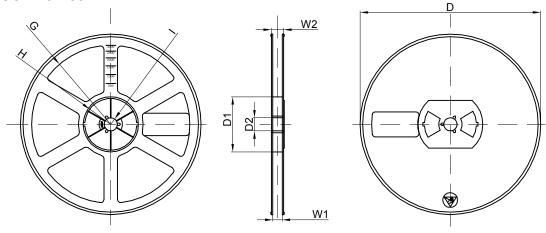
SOT-23 parts are shipped in tape. The carrier tape is made from a dissipative (carbon filled) polycarbonate resin. The cover tape is a multilayer film (Heat Activated Adhesive in nature) primarily composed of polyester film, adhesive layer, sealant, and anti-static sprayed agent. These reeled parts in standard option are shipped with 3,000 units per 7" or 17.8cm diameter reel. The reels are clear in color and is made of polystyrene plastic (anti-static coated).

| Dimensions are in millimeter | | | | | | | | | |
|--------------------------------|--|--|--|--|--|--|--|---|--|
| Pkg type A B C d E F P0 P P1 W | | | | | | | | W | |
| SOT-23 | | | | | | | | | |

SOT-23 Tape Leader and Trailer







| Dimensions are in millimeter | | | | | | | | | |
|---------------------------------|---------|-------|-------|--------|--------|-------|------|-------|--|
| Reel Option D D1 D2 G H I W1 W2 | | | | | | | | W2 | |
| 7"Dia | Ø178.00 | 54.40 | 13.00 | R78.00 | R25.60 | R6.50 | 9.50 | 12.30 | |

| REEL | Reel Size | Вох | Box Size(mm) | Carton | Carton Size(mm) | G.W.(kg) |
|----------|-----------|------------|--------------|-------------|-----------------|----------|
| 3000 pcs | 7 inch | 30,000 pcs | 203×203×195 | 120,000 pcs | 438×438×220 | |